Product Preview

Power MOSFET -2.48 Amps, -30 Volts

P-Channel Enhancement Mode Single Micro8 Package

Features

- Ultra Low R_{DS(on)}
- Higher Efficiency Extending Battery Life
- Miniature Micro8 Surface Mount Package
- Diode Exhibits High Speed, Soft Recovery
- Micro8 Mounting Information Provided

Applications

• Power Management in Portable and Battery–Powered Products, i.e.: Cellular and Cordless Telephones and PCMCIA Cards

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V_{DSS}	-30	V
Gate-to-Source Voltage - Continuous	V_{GS}	±20	V
Thermal Resistance – Junction–to–Ambient (Note 1.) Total Power Dissipation @ T _A = 25°C Continuous Drain Current @ T _A = 25°C Continuous Drain Current @ T _A = 70°C	R _{θJA} P _D I _D I _D	160 0.78 -2.48 -1.98	°C/W W A A
Thermal Resistance – Junction–to–Ambient (Note 2.) Total Power Dissipation @ T _A = 25°C Continuous Drain Current @ T _A = 25°C Continuous Drain Current @ T _A = 70°C	R _{θJA} P _D I _D	70 1.78 –3.75 –3.0	°C/W W A A
Thermal Resistance – Junction–to–Ambient (Note 3.) Total Power Dissipation @ T _A = 25°C Continuous Drain Current @ T _A = 25°C Continuous Drain Current @ T _A = 70°C Pulsed Drain Current (Note 5.)	R _{0JA} P _D I _D I _{DM}	210 0.60 -2.10 -1.67 -17	°C/W W A A
Thermal Resistance – Junction–to–Ambient (Note 4.) Total Power Dissipation @ T _A = 25°C Continuous Drain Current @ T _A = 25°C Continuous Drain Current @ T _A = 70°C Pulsed Drain Current (Note 5.)	R _{θJA} P _D I _D I _{DM}	100 1.25 -3.02 -2.42 -24	°C/W W A A
Operating and Storage Temperature Range	T _J , T _{stg}	–55 to +150	°C

- 1. Minimum FR-4 or G-10 PCB, Time ≤ 10 Seconds.
- Mounted onto a 2" square FR-4 Board (1" sq. 2 oz Cu 0.06" thick single sided), Time ≤ 10 Seconds.
- 3. Minimum FR-4 or G-10 PCB, Steady State.
- Mounted onto a 2" square FR-4 Board (1" sq. 2 oz Cu 0.06" thick single sided), Steady State.
- 5. Pulse Test: Pulse Width = 300 μs, Duty Cycle = 2%.

This document contains information on a product under development. ON Semiconductor reserves the right to change or discontinue this product without notice.

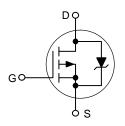


ON Semiconductor™

http://onsemi.com

-2.48 AMPERES -30 VOLTS 85 m Ω @ V_{GS} = -10 V

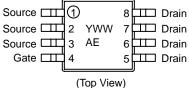
Single P-Channel





Micro8 CASE 846A STYLE 1

MARKING DIAGRAM & PIN ASSIGNMENT



` '

Y = Year WW = Work Week

AE = Device Code

ORDERING INFORMATION

Device	Package	Shipping	
NTTS2P03R2	Micro8	4000/Tape & Reel	

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted) (continued)

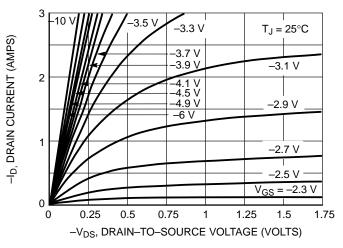
Rating	Symbol	Value	Unit
Single Pulse Drain–to–Source Avalanche Energy – Starting T_J = 25°C (V_{DD} = -30 Vdc, V_{GS} = -10 Vdc, Peak I_L = -3.0 Apk, L = 65 mH, R_G = 25 Ω)	E _{AS}	292.5	mJ
Maximum Lead Temperature for Soldering Purposes for 10 seconds	TL	260	°C

Characteristic			Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage Temperature Coefficient (Positive	V _{(BR)DSS}	-30 -	- -30	_ _	Vdc mV/°C	
Zero Gate Voltage Drain Current $(V_{GS} = 0 \text{ Vdc}, V_{DS} = -30 \text{ Vdc}, T_{J})$ $(V_{GS} = 0 \text{ Vdc}, V_{DS} = -30 \text{ Vdc}, T_{J})$	I _{DSS}	- -	_ _	-1.0 -25	μAdc	
Gate–Body Leakage Current (V _{GS} = –20 Vdc, V _{DS} = 0 Vdc)		I _{GSS}	-	-	-100	nAdc
Gate–Body Leakage Current (V _{GS} = +20 Vdc, V _{DS} = 0 Vdc)		I _{GSS}	-	-	100	nAdc
ON CHARACTERISTICS						
Gate Threshold Voltage (V _{DS} = V _{GS} Temperature Coefficient (Negativ		V _{GS(th)}	-1.0 -	-1.7 3.6	-3.0 -	Vdc
Static Drain-to-Source On-State F ($V_{GS} = -10$ Vdc, $I_D = -2.48$ Adc) ($V_{GS} = -4.5$ Vdc, $I_D = -1.24$ Adc)	R _{DS(on)}	_ _	0.063 0.100	0.085 0.135	Ω	
Forward Transconductance (V _{DS} =	-15 Vdc, I _D = -1.24 Adc)	9FS	-	3.1	_	Mhos
DYNAMIC CHARACTERISTICS		•		•		•
Input Capacitance		C _{iss}	-	500	_	pF
Output Capacitance	$(V_{DS} = -24 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, $ f = 1.0 MHz)	C _{oss}	-	160	_	
Reverse Transfer Capacitance] ,	C _{rss}	-	65	_]
SWITCHING CHARACTERISTICS (Notes 6. and 7.)					
Turn-On Delay Time		t _{d(on)}	-	10	_	ns
Rise Time	$(V_{DD} = -24 \text{ Vdc}, I_D = -2.48 \text{ Adc},$	t _r	-	20	-	
Turn-Off Delay Time	$V_{GS} = -10 \text{ Vdc}, R_G = 6.0 \Omega)$	t _{d(off)}	-	40	-	
Fall Time		t _f	-	35	_	
Turn-On Delay Time		t _{d(on)}	-	16	_	ns
Rise Time	$(V_{DD} = -24 \text{ Vdc}, I_D = -1.24 \text{ Adc},$	t _r	-	40	_	
Turn-Off Delay Time	$V_{GS} = -4.5 \text{ Vdc}, R_G = 6.0 \Omega)$	t _{d(off)}	-	30	_	
Fall Time		t _f	-	30	_	1
Total Gate Charge	(V _{DS} = -24 Vdc,	Q _{tot}	-	15	22	nC
Gate-Source Charge	$V_{GS} = -4.5 \text{ Vdc},$	Q _{gs}	-	3.2	-	
Gate-Drain Charge	$I_D = -2.48 \text{ Adc}$	Q _{gd}	-	4.0	-	
BODY-DRAIN DIODE RATINGS (No	ote 6.)					•
Diode Forward On-Voltage	$(I_S = -2.48 \text{ Adc}, V_{GS} = 0 \text{ Vdc})$ $(I_S = -2.48 \text{ Adc}, V_{GS} = 0 \text{ Vdc},$ $T_J = 125^{\circ}\text{C})$	V _{SD}	<u>-</u>	-0.92 -0.72	-1.3 -	Vdc
Reverse Recovery Time		t _{rr}	_	38	_	ns
	$(I_S = -1.45 \text{ Adc}, V_{GS} = 0 \text{ Vdc},$	t _a	_	20	_	
	$dl_S/dt = 100 A/\mu s)$	t _b	_	18	_	
Reverse Recovery Stored Charge		Q _{RR}	_	0.04	_	μС

^{6.} Indicates Pulse Test: Pulse Width = 300 μ sec max, Duty Cycle = 2%.

^{7.} Switching characteristics are independent of operating junction temperature.

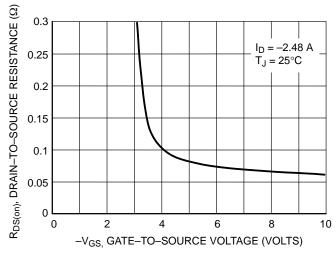
^{*} Handling precautions to protect against electrostatic discharge is mandatory.



SQUANT STATE OF TOOLS AND STATE

Figure 1. On-Region Characteristics

Figure 2. Transfer Characteristics



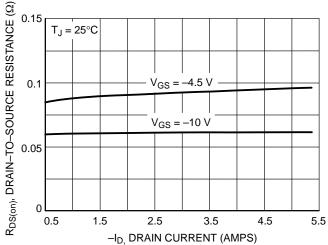
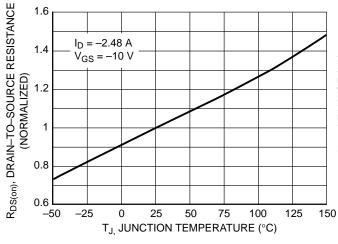


Figure 3. On–Resistance versus Gate–to–Source Voltage

Figure 4. On–Resistance versus Drain Current and Gate Voltage



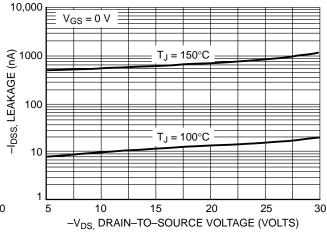
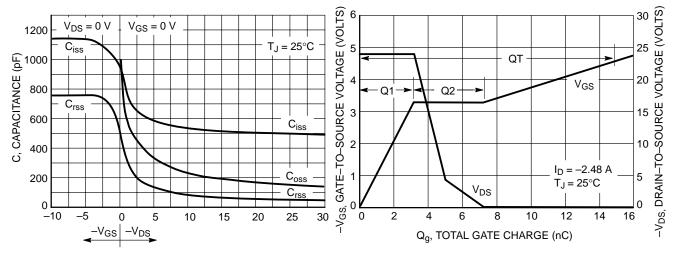


Figure 5. On–Resistance Variation with Temperature

Figure 6. Drain-to-Source Leakage Current versus Voltage



GATE-TO-SOURCE OR DRAIN-TO-SOURCE VOLTAGE (VOLTS)

Figure 7. Capacitance Variation

Figure 8. Gate-to-Source and Drain-to-Source Voltage versus Total Charge

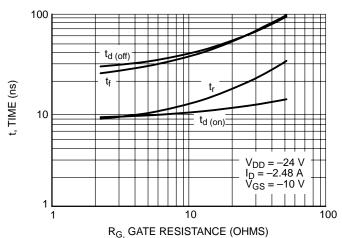


Figure 9. Resistive Switching Time Variation versus Gate Resistance

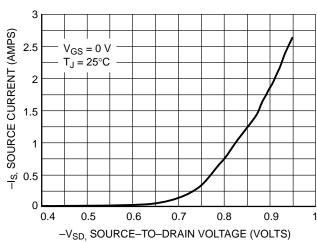


Figure 10. Diode Forward Voltage versus Current

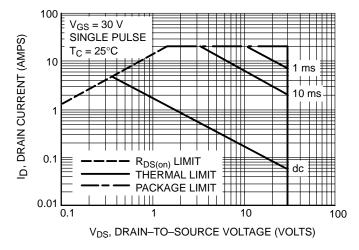


Figure 11. Maximum Rated Forward Biased Safe Operating Area

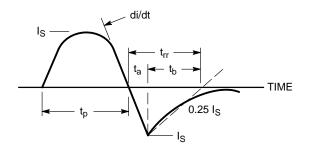


Figure 12. Diode Reverse Recovery Waveform

TYPICAL ELECTRICAL CHARACTERISTICS

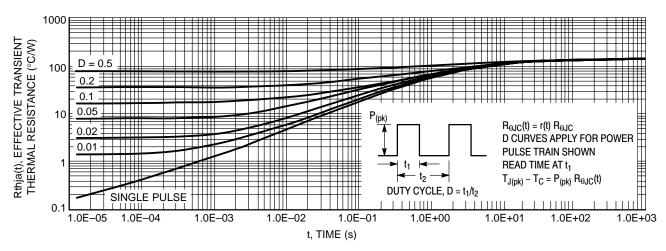
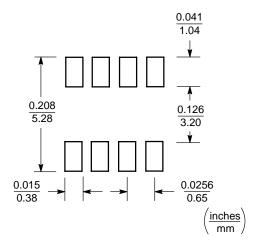


Figure 13. Thermal Response

INFORMATION FOR USING THE Micro8 SURFACE MOUNT PACKAGE

MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to ensure proper solder connection interface between the board and the package. With the correct pad geometry, the packages will self-align when subjected to a solder reflow process.



SOLDERING PRECAUTIONS

The melting temperature of solder is higher than the rated temperature of the device. When the entire device is heated to a high temperature, failure to complete soldering within a short time could result in device failure. Therefore, the following items should always be observed in order to minimize the thermal stress to which the devices are subjected.

- Always preheat the device.
- The delta temperature between the preheat and soldering should be 100°C or less.*
- When preheating and soldering, the temperature of the leads and the case must not exceed the maximum temperature ratings as shown on the data sheet. When using infrared heating with the reflow soldering method, the difference shall be a maximum of 10°C.

- The soldering temperature and time shall not exceed 260°C for more than 10 seconds.
- When shifting from preheating to soldering, the maximum temperature gradient shall be 5°C or less.
- After soldering has been completed, the device should be allowed to cool naturally for at least three minutes.
 Gradual cooling should be used as the use of forced cooling will increase the temperature gradient and result in latent failure due to mechanical stress.
- Mechanical stress or shock should not be applied during cooling.
- * Soldering a device without preheating can cause excessive thermal shock and stress which can result in damage to the device.

TYPICAL SOLDER HEATING PROFILE

For any given circuit board, there will be a group of control settings that will give the desired heat pattern. The operator must set temperatures for several heating zones and a figure for belt speed. Taken together, these control settings make up a heating "profile" for that particular circuit board. On machines controlled by a computer, the computer remembers these profiles from one operating session to the next. Figure 14 shows a typical heating profile for use when soldering a surface mount device to a printed circuit board. This profile will vary among soldering systems, but it is a good starting point. Factors that can affect the profile include the type of soldering system in use, density and types of components on the board, type of solder used, and the type of board or substrate material being used. This profile shows

temperature versus time. The line on the graph shows the actual temperature that might be experienced on the surface of a test board at or near a central solder joint. The two profiles are based on a high density and a low density board. The Vitronics SMD310 convection/infrared reflow soldering system was used to generate this profile. The type of solder used was 62/36/2 Tin Lead Silver with a melting point between 177–189°C. When this type of furnace is used for solder reflow work, the circuit boards and solder joints tend to heat first. The components on the board are then heated by conduction. The circuit board, because it has a large surface area, absorbs the thermal energy more efficiently, then distributes this energy to the components. Because of this effect, the main body of a component may be up to 30 degrees cooler than the adjacent solder joints.

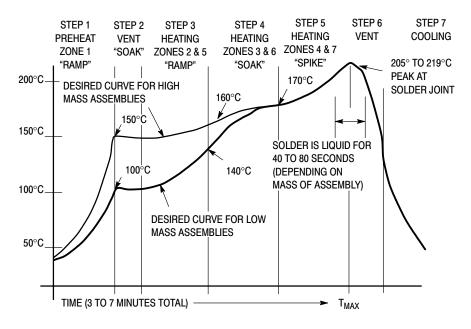
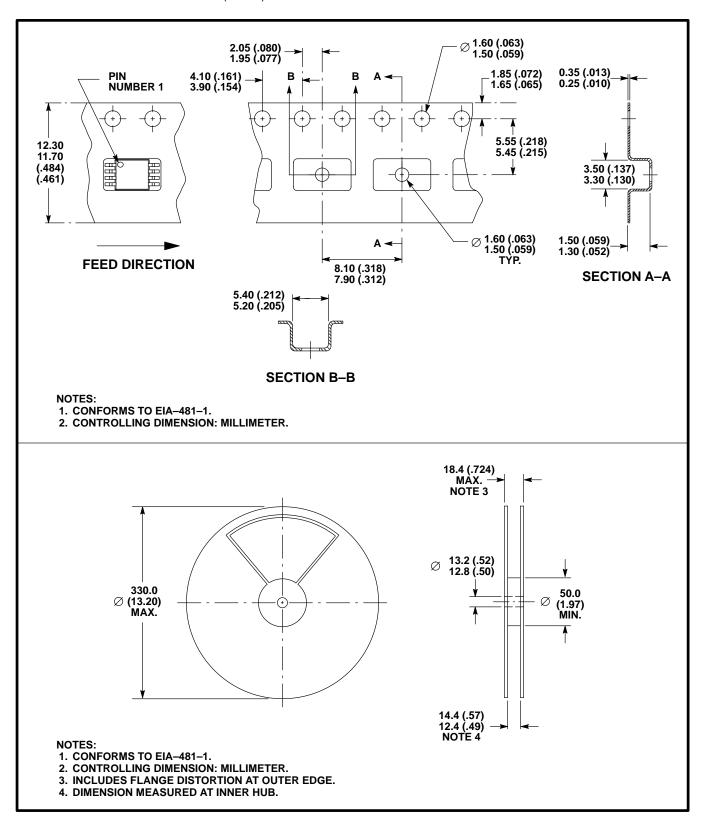


Figure 14. Typical Solder Heating Profile.

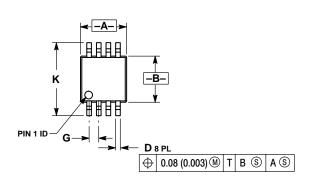
TAPE & REEL INFORMATION

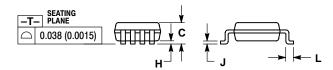
Micro-8Dimensions are shown in millimeters (inches)



PACKAGE DIMENSIONS

Micro8 CASE 846A-02 ISSUE E





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETER.
- DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT
- EXCEED 0.15 (0.006) PER SIDE.

 DIMENSION B DOES NOT INCLUDE INTERLEAD
 FLASH OR PROTRUSION. INTERLEAD FLASH OR
 PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE

	MILLIMETERS INCHES			HES
DIM	MIN	MAX	MIN	MAX
Α	2.90	3.10	0.114	0.122
В	2.90	3.10	0.114	0.122
C		1.10		0.043
D	0.25	0.40	0.010	0.016
G	0.65 BSC		0.026 BSC	
Н	0.05	0.15	0.002	0.006
J	0.13	0.23	0.005	0.009
K	4.75	5.05	0.187	0.199
L	0.40	0.70	0.016	0.028

STYLE 1:

PIN 1. SOURCE

- 2. SOURCE SOURCE
- 4. GATE 5. DRAIN DRAIN
- 6. DRAIN
- DRAIN
- DRAIN

are trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes ON Semiconductor and without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular without during the statistics of any products releast. Solicition makes its warranty, representation of guarantee regarding the statistics of any product or any product or any product or any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer.

PUBLICATION ORDERING INFORMATION

NORTH AMERICA Literature Fulfillment:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA

Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada

Email: ONlit@hibbertco.com

Fax Response Line: 303-675-2167 or 800-344-3810 Toll Free USA/Canada

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

EUROPE: LDC for ON Semiconductor - European Support

German Phone: (+1) 303-308-7140 (Mon-Fri 2:30pm to 7:00pm CET) Email: ONlit-german@hibbertco.com

Phone: (+1) 303–308–7141 (Mon–Fri 2:00pm to 7:00pm CET)

Email: ONlit-french@hibbertco.com

English Phone: (+1) 303-308-7142 (Mon-Fri 12:00pm to 5:00pm GMT)

Email: ONlit@hibbertco.com

EUROPEAN TOLL-FREE ACCESS*: 00-800-4422-3781

*Available from Germany, France, Italy, UK, Ireland

CENTRAL/SOUTH AMERICA:

Spanish Phone: 303-308-7143 (Mon-Fri 8:00am to 5:00pm MST)

Email: ONlit-spanish@hibbertco.com

Toll-Free from Mexico: Dial 01-800-288-2872 for Access -

then Dial 866-297-9322

ASIA/PACIFIC: LDC for ON Semiconductor - Asia Support

Phone: 303-675-2121 (Tue-Fri 9:00am to 1:00pm, Hong Kong Time)

Toll Free from Hong Kong & Singapore:

001-800-4422-3781 Email: ONlit-asia@hibbertco.com

JAPAN: ON Semiconductor, Japan Customer Focus Center 4-32-1 Nishi-Gotanda, Shinagawa-ku, Tokyo, Japan 141-0031

Phone: 81-3-5740-2700 Email: r14525@onsemi.com

ON Semiconductor Website: http://onsemi.com

For additional information, please contact your local

Sales Representative.